Product data sheet

1. Product profile

1.1 General description

The KMZ41 is a sensitive magnetic field sensor, employing the magneto-resistive effect of thin film permalloy. The sensor contains two galvanic separated Wheatstone bridges, which enclose an angle of 45 degrees.

A rotating magnetic field strength > 40 kA/m (recommended field strength > 100 kA/m) in the surface parallel to the chip (x-y plane) will deliver two independent sinusoidal output signals, one following a $\cos(2\alpha)$ and the second following a $\sin(2\alpha)$ function.

The sensor can be operated at any frequency between DC and 1 MHz.

Application notes *AN00023* (contactless angle measurement using KMZ41 and UZZ9000) and *AN00004* (contactless angle measurement using KMZ41 and UZZ9001) are available.

1.2 Features

- Accurate and reliable angle measurement
- Mechanical robustness, contactless principle
- Wear-free operation
- Accuracy independent on mechanical tolerances
- Extended temperature range

1.3 Quick reference data

Table 1. Quick reference data

 T_{amb} = 25 °C and H_{ext} = 100 kA/m, V_{CC} = 5 V unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		[1] _	5	9	V
V_{peak}	peak voltage	see Figure 2	[1] 70	78	86	mV
V _{offset}	offset voltage	per supply voltage; see Figure 2	<u>[1]</u> –2	-	+2	mV/V
R _{bridge}	bridge resistance		[1][2] 2.0	2.5	3.0	kΩ

^[1] Applicable for bridge 1 and bridge 2.



^[2] Bridge resistance between pin 4 to pin 8, pin 3 to pin 7, pin 5 to pin 1 and pin 6 to pin 2.

Magnetic field sensor

2. Pinning information

Table 2. Pinning

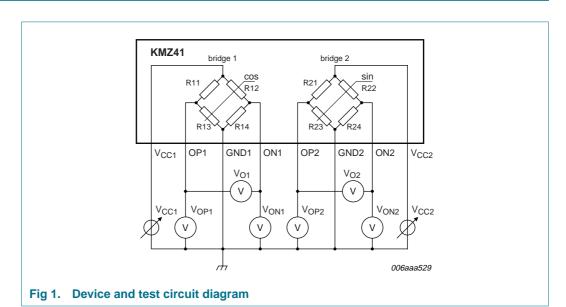
Pin	Symbol	Description	Simplified outline
1	ON1	output voltage bridge 1	_
2	ON2	output voltage bridge 2	⁸ ДДДБ Х
3	V_{CC2}	supply voltage bridge 2	
4	V _{CC1}	supply voltage bridge 1	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
5	OP1	output voltage bridge 1	mgd790
6	OP2	output voltage bridge 2	
7	GND2	supply voltage bridge 2	
8	GND1	supply voltage bridge 1	

3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
KMZ41	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1	

4. Circuit diagram



Magnetic field sensor

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		<u>[1]</u> _	9	V
H _{ext}	external magnetic field strength		40	-	kA/m
T _{amb}	ambient temperature		-40	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Applicable for bridge 1 and bridge 2.

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-a)}	thermal resistance from junction to ambient		155	K/W

Magnetic field sensor

7. Characteristics

Table 6. Characteristics

 T_{amb} = 25 °C and H_{ext} = 100 kA/m, V_{CC} = 5 V unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CC}	supply voltage		<u>[1]</u>	-	5	9	V
V_{peak}	peak voltage	see Figure 2	<u>[1]</u>	70	78	86	mV
TCV _{peak}	temperature coefficient of peak voltage	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +150 ^{\circ}\text{C}$	[1][2]	-0.38	-0.41	-0.44	%/K
R _{bridge}	bridge resistance		[1][3]	2.0	2.5	3.0	kΩ
TCR _{bridge}	temperature coefficient of bridge resistance	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +150 ^{\circ}\text{C}$	[1][4]	0.31	0.33	0.35	%/K
V _{offset}	offset voltage	per supply voltage; see <u>Figure 2</u>	[1]	-2	-	+2	mV/V
TCV _{offset}	temperature coefficient of offset voltage	per supply voltage; $T_{amb} = -40 ^{\circ}\text{C} \text{ to } +150 ^{\circ}\text{C};$ see Figure 2	[1][5]	-2	-	+2	(μV/V)/K
FH	hysteresis of output voltage	see Figure 3	[1][6]	0	0.01	0.04	%FS
k	amplitude synchronism		<u>[7]</u>	99	100	101	%
TCk	temperature coefficient of amplitude synchronism	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +150 ^{\circ}\text{C}$	[8]	-0.005	0	+0.005	%/K
Δα	angular inaccuracy		[9]	0	0.1	0.25	deg

[1] Applicable for bridge 1 and bridge 2.

[2]
$$TCV_{peak} = 100 \times \frac{V_{peak}(at\ 150\ ^{\circ}C) - V_{peak}(at\ -40\ ^{\circ}C)}{V_{peak}(at\ 25\ ^{\circ}C) \times (150\ ^{\circ}C - (-40\ ^{\circ}C))}$$

[3] Bridge resistance between pin 4 to pin 8, pin 3 to pin 7, pin 5 to pin 1 and pin 6 to pin 2.

[4]
$$TCR_{bridge} = 100 \times \frac{R_{bridge}(at\ 150\ ^{\circ}C) - R_{bridge}(at\ -40\ ^{\circ}C)}{R_{bridge}(at\ 25\ ^{\circ}C) \times (150\ ^{\circ}C - (-40\ ^{\circ}C))}$$

[5]
$$TCV_{offset} = \frac{V_{offset}(at\ 150\ ^{\circ}C) - V_{offset}(at\ -40\ ^{\circ}C)}{150\ ^{\circ}C - (-40\ ^{\circ}C)}$$

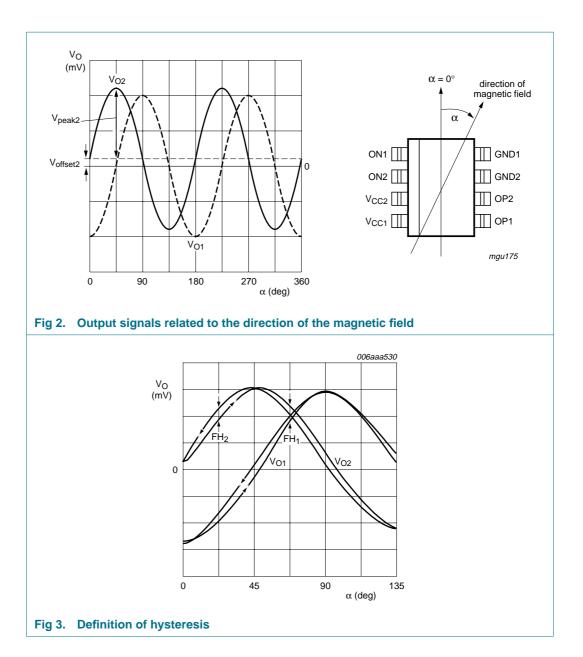
$$\begin{split} [6] \quad FH_1 &= 100 \times \left| \frac{V_{O1}(67.5^\circ)135^\circ {\to} 45^\circ - V_{O1}(67.5^\circ)45^\circ {\to} 135^\circ}{2 \times V_{peak1}} \right| \\ FH_2 &= 100 \times \left| \frac{V_{O2}(22.5^\circ)90^\circ {\to} 0^\circ - V_{O2}(22.5^\circ)0^\circ {\to} 90^\circ}{2 \times V_{peak2}} \right| \end{split}$$

[7]
$$k = 100 \times \frac{V_{peak1}}{V_{peak2}}$$

[8]
$$TCk = 100 \times \frac{k(at\ 150\ ^{\circ}C) - k(at\ -40\ ^{\circ}C)}{k(at\ 25\ ^{\circ}C) \times (150\ ^{\circ}C - (-40\ ^{\circ}C))}$$

[9] $\Delta \alpha = |\alpha_{\text{real}} - \alpha_{\text{meas}}|$; $V_{\text{offset}} = 0 \text{ V}$; inaccuracy of angular measurement due to deviations from ideal sinusoidal characteristics, calculated from the third and fifth harmonies of the spectrum of V_{O} .

Magnetic field sensor



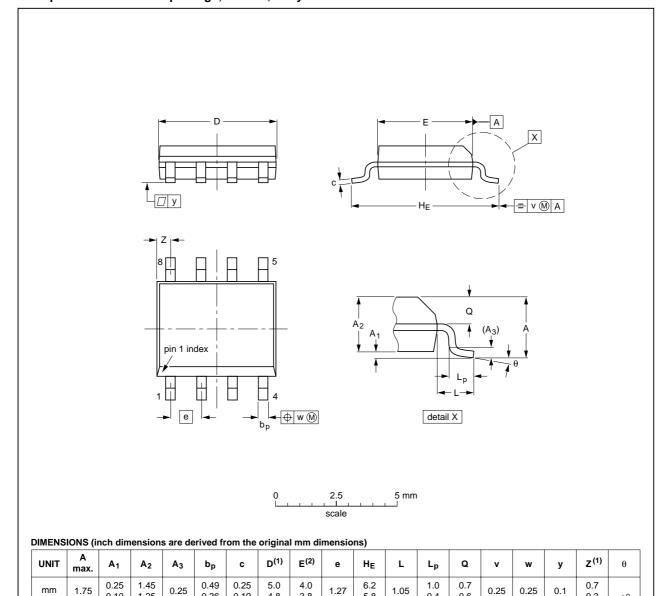
KMZ41 **NXP Semiconductors**

Magnetic field sensor

Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



inches

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.36

0.19

0.019 0.0100

0.014 0.0075

4.8

0.20

3.8

0.16

0.15

2. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

	REFER	ENCES	EUROPEAN ISSUE DAT	ISSUE DATE
IEC	JEDEC	JEITA	PROJECTION ISSUE DA	
076E03	MS-012			99-12-27 03-02-18
	_	IEC JEDEC	IEC JEDEC JEITA	IEC JEDEC JEITA PROJECTION

0.05

5.8

0.244

0.228

0.041

0.4

0.039

0.016

0.6

0.028

0.024

0.01

0.01

0.3

0.028

0.004

00

Fig 4. Package outline SOT96-1 (SO8/MS-012)

1.25

0.057

0.049

0.01

0.10

0.010

0.004

0.069

Magnetic field sensor

9. Packing information

Table 7. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	ype number Package Description		Packing quantity
			2500
KMZ41	SOT96-1	8 mm pitch, 12 mm tape and reel	-118

^{[1] 12}NC ordering code: 9340 372 10118. For further information and the availability of packing methods, see Section 12.

10. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
KMZ41_5	20061127	Product data sheet	-	KMZ41_4			
Modifications:		of this data sheet has been of NXP Semiconductors.	redesigned to comply v	with the new identity			
	 Legal texts have been adapted to the new company name where appropriate. 						
	Section 1.1 "General description": amended						
	Section 1.2 "Features": added						
	Table 1 "Quick reference data": V _{peak} peak voltage added						
	Table 1: R _{bridge} bridge resistance Table note 2 added						
	Table 2 "Pinning": amended Table 2 "Pinning": amended						
	Section 3 "Ordering information": added						
	Figure 1 "Device and test circuit diagram": amended						
	Table 4 "Limiting values": H _{ext} external magnetic field strength added						
	Table 4: T _{bridge} bridge operating temperature redefined to T _{amb} ambient temperature						
		aracteristics": H _{rotation} rede					
	Figure 3 "Definition of hysteresis": added						
		Packing information": added					
KMZ41_4	20000418	Preliminary specification		KMZ41_3			

Magnetic field sensor

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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